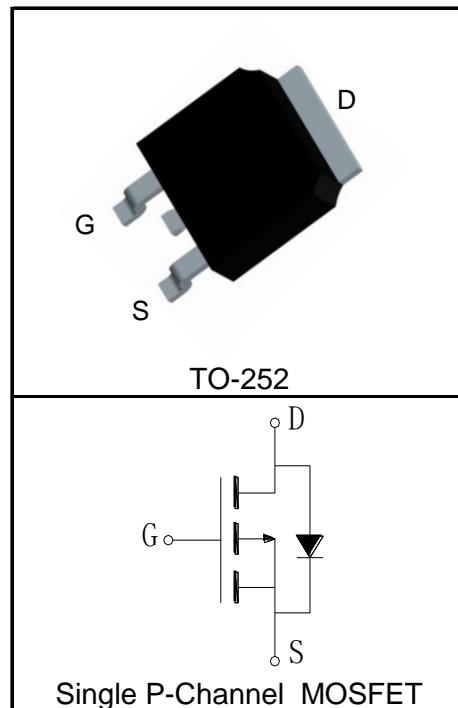


Features

- -30V/-70A,
 $R_{DS(ON)} = 6.5\text{m}\Omega$ (Typ.)@ $V_{GS}=-10\text{V}$
- $R_{DS(ON)} = 9\text{m}\Omega$ (Typ.)@ $V_{GS}=-4.5\text{V}$
- Low $R_{DS(ON)}$
- Super High Dense Cell Design
- Reliable and Rugged

Pin Description



Applications

- Power Switching Application
- Load Switching



Halogen-Free

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
Common Ratings ($T_c=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	-30	V
V_{GSS}	Gate-Source Voltage	± 20	
T_J	Maximum Junction Temperature	175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 175	$^\circ\text{C}$
I_S	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$	-70
Mounted on Large Heat Sink			
$I_{DP}^{①}$	300 μs Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	-280
$I_D^{②}$	Continuous Drain Current($V_{GS}=-10\text{V}$)	$T_c=25^\circ\text{C}$	-70
		$T_c=100^\circ\text{C}$	-49
P_D	Maximum Power Dissipation	$T_c=25^\circ\text{C}$	75
		$T_c=100^\circ\text{C}$	37
$R_{\theta JC}$	Thermal Resistance-Junction to Case	2	$^\circ\text{C/W}$
$R_{\theta JA}^{③}$	Thermal Resistance-Junction to Ambient	100	$^\circ\text{C/W}$
Drain-Source Avalanche Ratings			
$E_{AS}^{④}$	Avalanche Energy, Single Pulsed	25	mJ

Electrical Characteristics ($T_C=25^\circ\text{C}$ Unless Otherwise Noted)

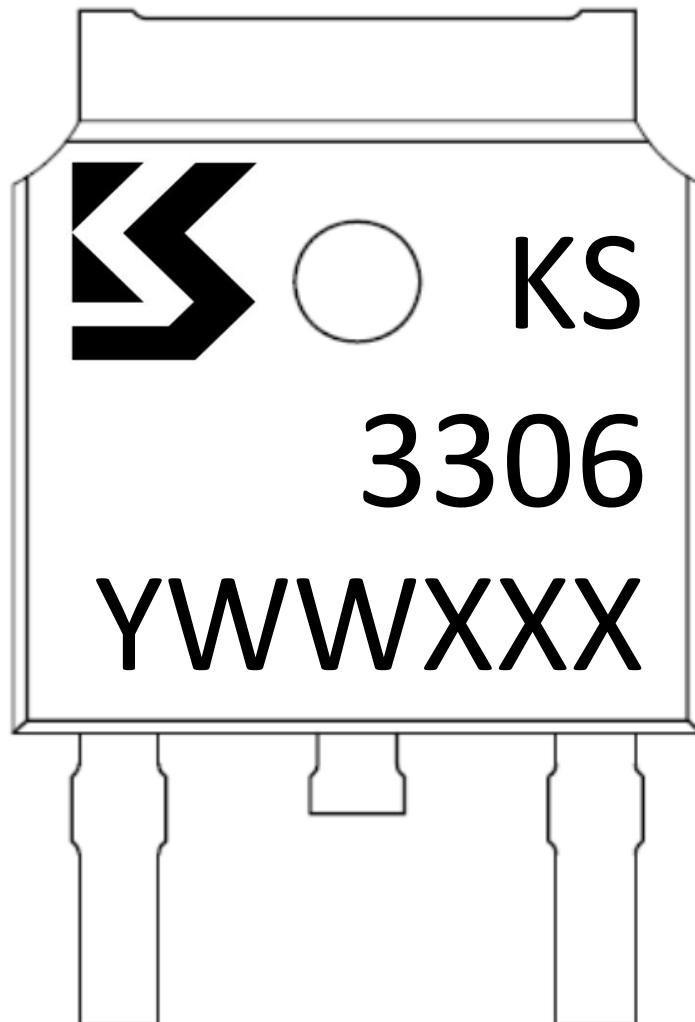
Symbol	Parameter	Test Condition	KS3306DB			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_{\text{DS}}=-250\mu\text{A}$	-30			V
I_{DSS}	Zero Gate Voltage Drain Current	$\text{V}_{\text{DS}}=-30\text{V}, \text{V}_{\text{GS}}=0\text{V}$			-1	μA
		$\text{T}_J=125^\circ\text{C}$			-30	
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_{\text{DS}}=-250\mu\text{A}$	-1.1	-1.5	-2.3	V
I_{GSS}	Gate Leakage Current	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$			± 100	nA
$\text{R}_{\text{DS}(\text{ON})}^{(5)}$	Drain-Source On-state Resistance	$\text{V}_{\text{GS}}=-10\text{V}, \text{I}_{\text{DS}}=-20\text{A}$		6.5	8	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=-4.5\text{V}, \text{I}_{\text{DS}}=-16\text{A}$		9	12	$\text{m}\Omega$
Diode Characteristics						
$\text{V}_{\text{SD}}^{(5)}$	Diode Forward Voltage	$\text{I}_{\text{SD}}=-20\text{A}, \text{V}_{\text{GS}}=0\text{V}$		-0.86	-1.2	V
t_{rr}	Reverse Recovery Time	$\text{I}_{\text{SD}}=-20\text{A}, \frac{d\text{I}_{\text{SD}}}{dt}=-100\text{A}/\mu\text{s}$		34		ns
Q_{rr}	Reverse Recovery Charge			79		nC
Dynamic Characteristics ⁽⁶⁾						
R_G	Gate Resistance	$\text{V}_{\text{GS}}=0\text{V}, \text{V}_{\text{DS}}=0\text{V}, \text{F}=1\text{MHz}$		3.4		Ω
C_{iss}	Input Capacitance	$\text{V}_{\text{GS}}=0\text{V}, \text{V}_{\text{DS}}=-15\text{V}, \text{Frequency}=1.0\text{MHz}$		4750		pF
C_{oss}	Output Capacitance			545		
C_{rss}	Reverse Transfer Capacitance			490		
$\text{t}_{\text{d}(\text{ON})}$	Turn-on Delay Time	$\text{V}_{\text{DD}}=-15\text{V}, \text{I}_{\text{DS}}=-20\text{A}, \text{V}_{\text{GEN}}=-10\text{V}, \text{R}_G=3\Omega$		182		ns
t_{r}	Turn-on Rise Time			262		
$\text{t}_{\text{d}(\text{OFF})}$	Turn-off Delay Time			580		
t_{f}	Turn-off Fall Time			375		
Gate Charge Characteristics ⁽⁶⁾						
Q_g	Total Gate Charge	$\text{V}_{\text{DS}}=-15\text{V}, \text{V}_{\text{GS}}=-10\text{V}, \text{I}_{\text{DS}}=-20\text{A}$		89		nC
Q_{gs}	Gate-Source Charge			14		
Q_{gd}	Gate-Drain Charge			19		

Notes:

- (1)Pulse width limited by safe operating area.
- (2)Calculated continuous current based on maximum allowable junction temperature. The package limitation current is -60A.
- (3)When mounted on 1 inch square copper board, $t \leq 10\text{sec}$. The value in any given application depends on the user's specific board design.
- (4)Limited by $\text{T}_{\text{Jmax}}, \text{I}_{\text{AS}} = -24\text{A}, \text{L}=0.5\text{mH}, \text{V}_{\text{DD}} = -15\text{V}, \text{R}_G = 25\Omega$, Starting $\text{TJ} = 25^\circ\text{C}$.
- (5)Pulse test; Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
- (6)Guaranteed by design, not subject to production testing.

Ordering and Marking Information

Device	Package	Packaging	Quantity	Reel Size	Tape width
KS3306DB	TO-252	Tape&Reel	2500	13"	16mm

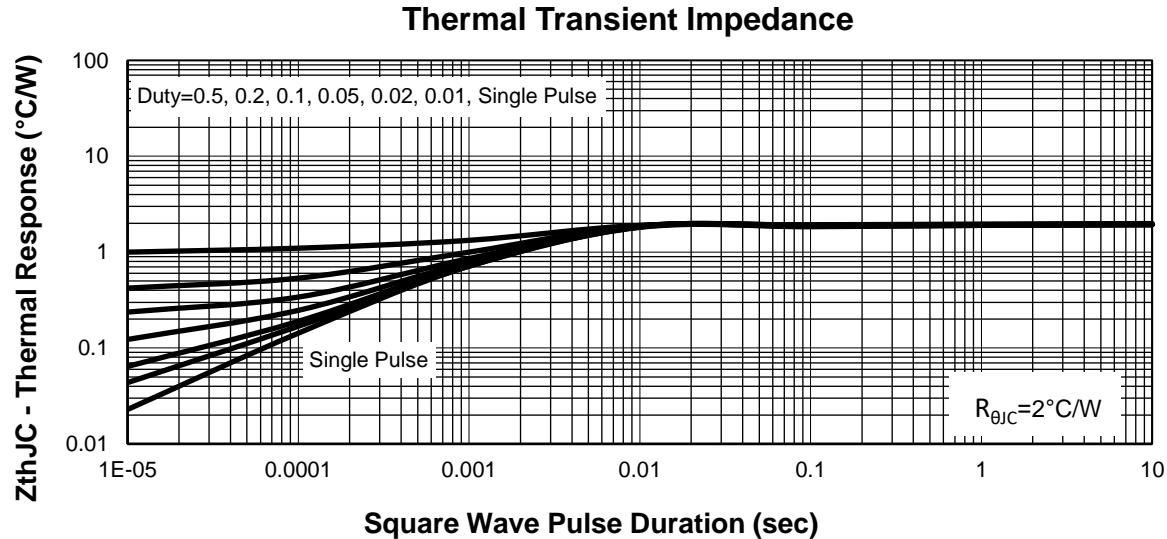
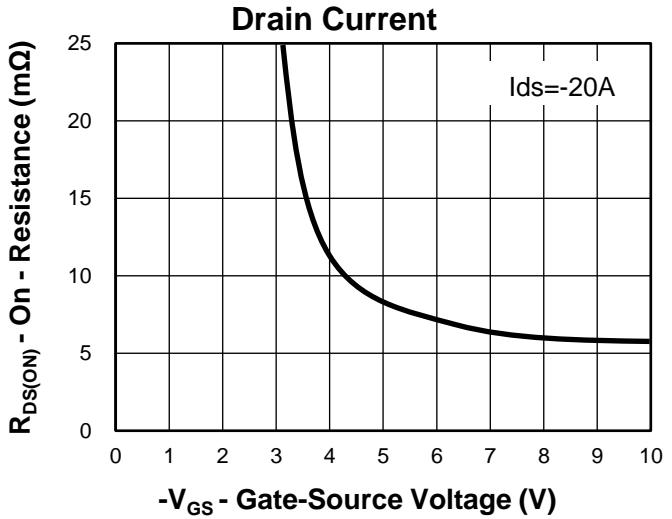
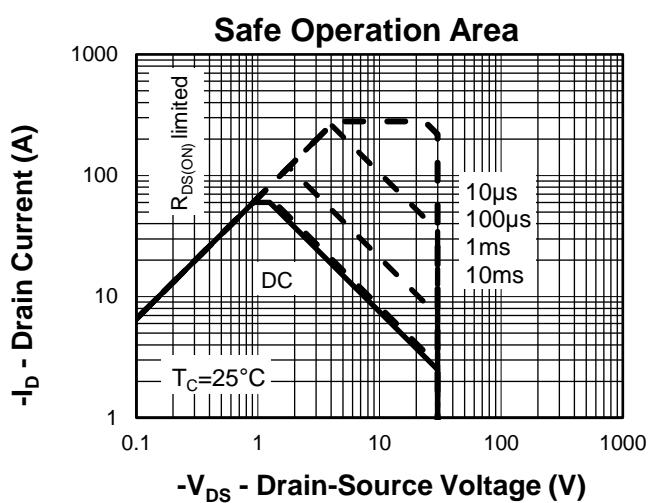
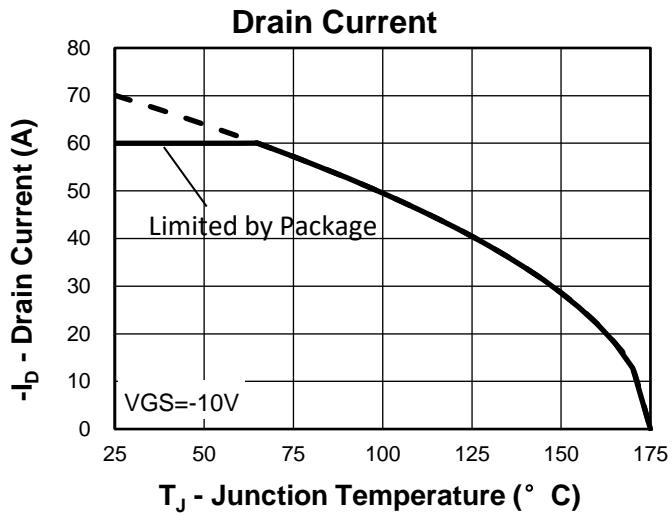
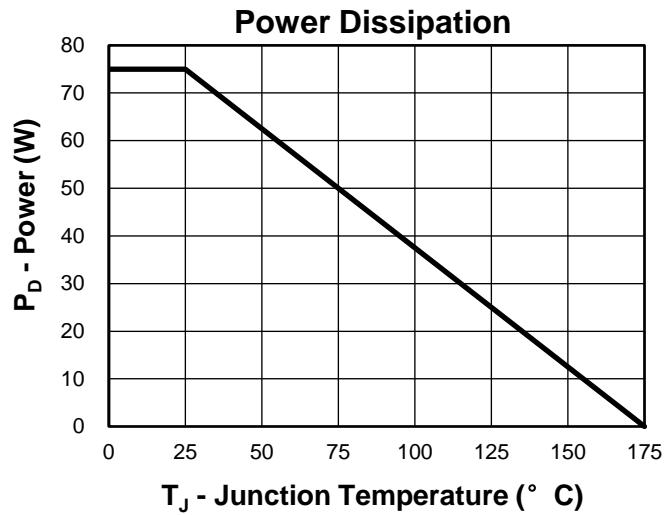


Y =Year, 2017-A, 2018-B,etc.

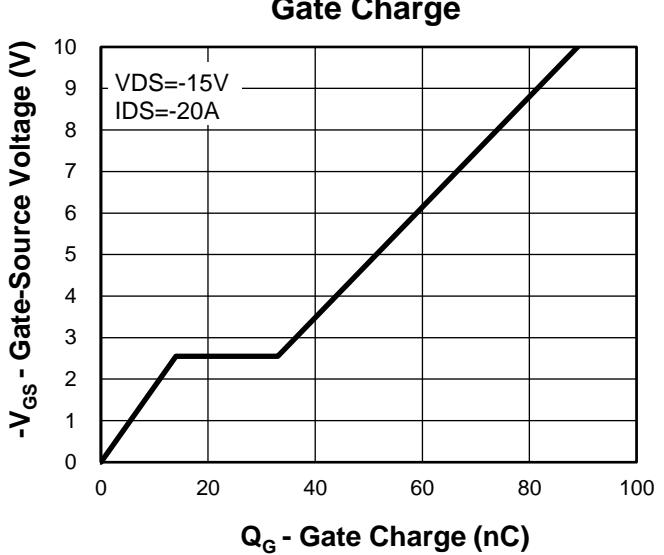
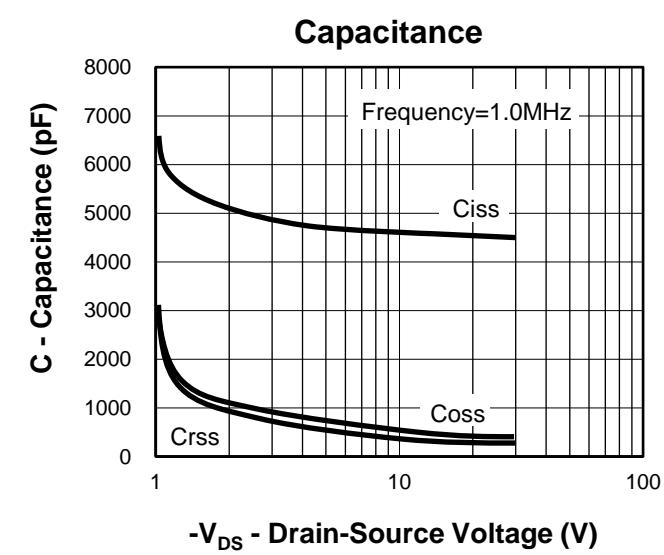
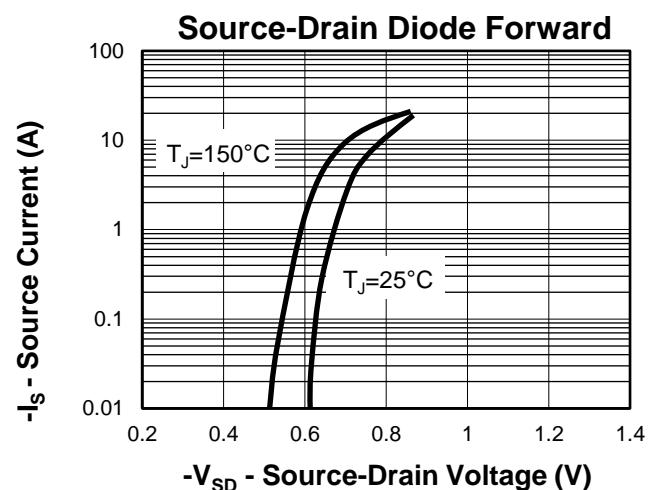
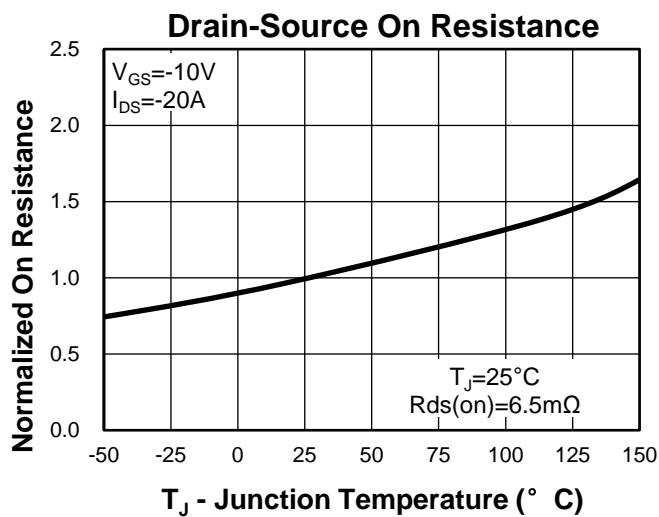
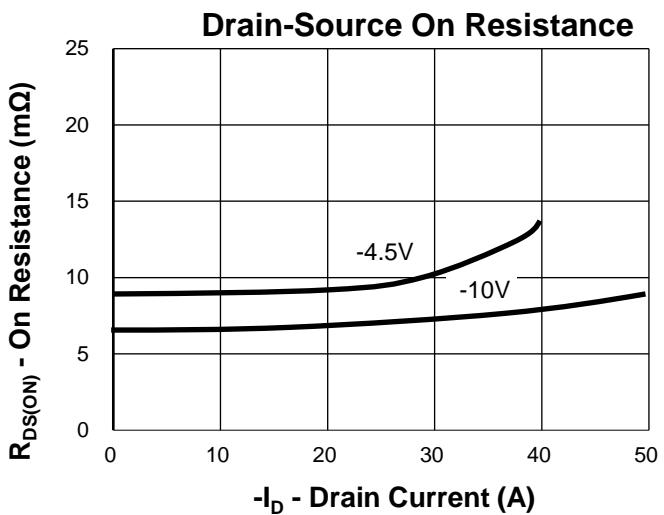
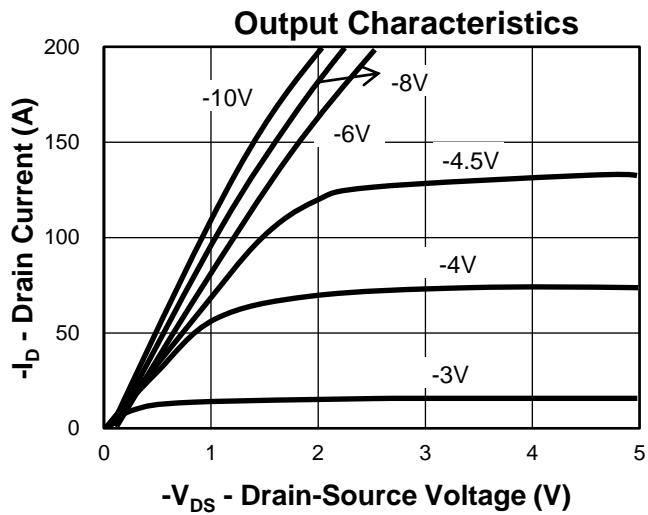
WW =Week.

XXX =Lot number.

Typical Characteristics

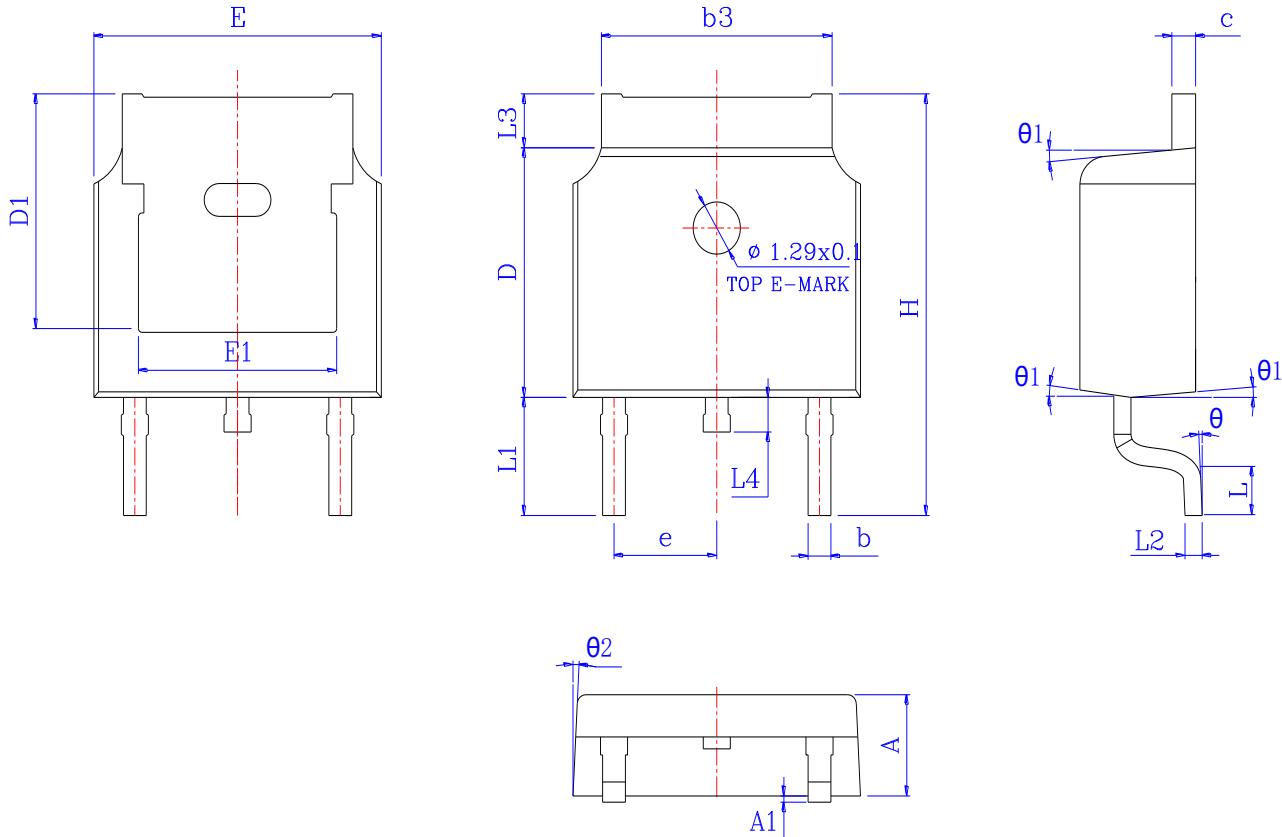


Typical Characteristics



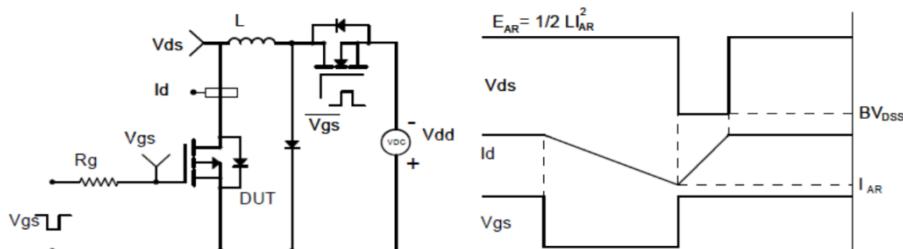
Package Information

TO-252

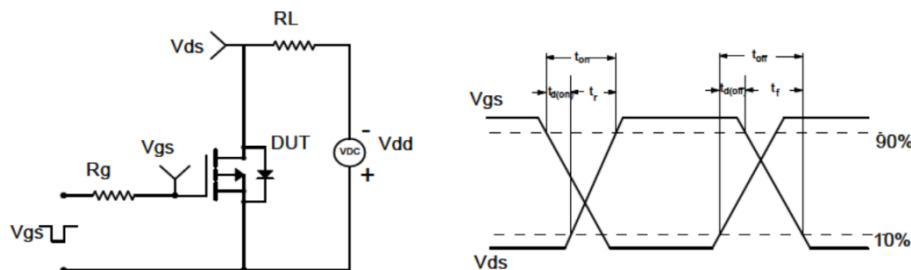


SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	2.200	2.300	2.400	0.087	0.091	0.094
A1	*	*	0.100	*	*	0.004
b	0.660	0.760	0.860	0.026	0.030	0.034
b3	5.130	5.295	5.460	0.202	0.208	0.215
c	0.470	0.535	0.600	0.019	0.021	0.024
D	6.000	6.100	6.200	0.236	0.240	0.244
D1	5.30 REF			0.20 REF		
E	6.500	6.600	6.700	0.256	0.260	0.264
E1	4.700	4.810	4.920	0.185	0.189	0.194
e	2.28 REF			0.09 REF		
H	9.800	10.100	10.400	0.386	0.398	0.409
L	1.400	1.550	1.700	0.055	0.061	0.067
L1	2.743 REF			0.108 REF		
L2	0.510 BSC			0.020 BSC		
L3	0.900	1.075	1.250	0.035	0.042	0.049
L4	0.600	0.800	1.000	0.024	0.031	0.039
θ	0°	*	8°	0°	*	8°
θ 1	5°	7°	9°	5°	7°	9°
θ 2	5°	7°	9°	5°	7°	9°

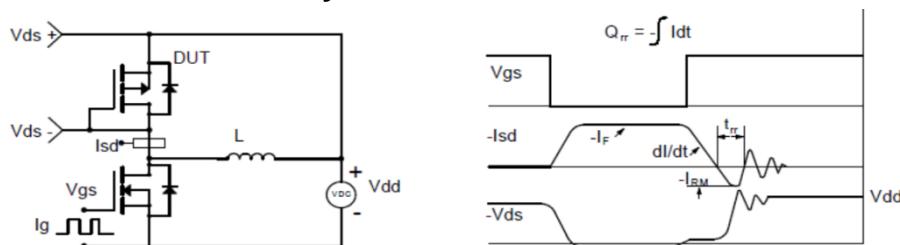
Avalanche Test Circuit and Waveforms



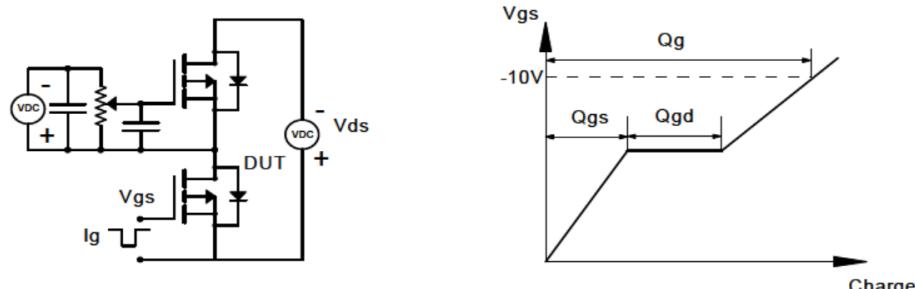
Switching Time Test Circuit and Waveforms



Diode Recovery Test Circuit and Waveforms



Gate Charge Test Circuit and Waveform



Customer Service

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